

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

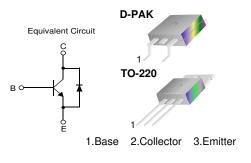
December 2009

FAIRCHILD

KSC5402D/KSC5402DT NPN Silicon Transistor, Planar Silicon Transistor

Features

- High Voltage High Speed Power Switch Application
- Wide Safe Operating Area
- Built-in Free Wheeling Diode
- Suitable for Electronic Ballast Application
- Small Variance in Storage Time
- Two Package Choices; D-PAK or TO-220



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	1000	V	
V _{CEO}	Collector-Emitter Voltage	450	V	
V _{EBO}	Emitter-Base Voltage	12	V	
Ι _C	Collector Current (DC)	2	A	
I _{CP}	*Collector Current (Pulse)	5	А	
I _B	Base Current (DC)	1	А	
I _{BP}	*Base Current (Pulse)	2	А	
P _C	Power Dissipation(T _C =25°C) : D-PAK* : TO-220	30 50	W W	
Т _Ј	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 65 to 150	°C	

* Pulse Test: Pulse Width=5ms, Duty Cycle≤10%

Thermal Characteristics T_A=25°C unless otherwise noted

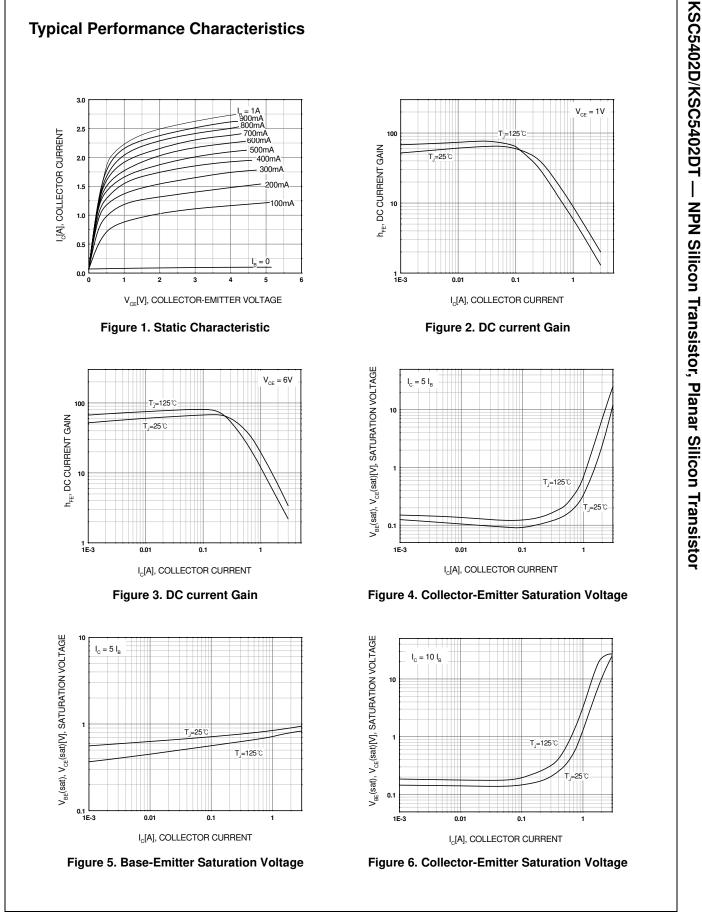
Symbol	Parameter		Rat	Units	
			TO-220	D-PAK	
R _{θJC}	Thermal Resistance	Junction to Case	2.5	4.17*	°C/W
R _{0JA}		Junction to Ambient	62.5	50	°C/W
TL	Maximum Lead Temper ; 1/8" from Case for 5 S	ature for Soldering Purpose seconds	270	270	°C

* Mounted on 1" square PCB (FR4 ro G-10 Material)

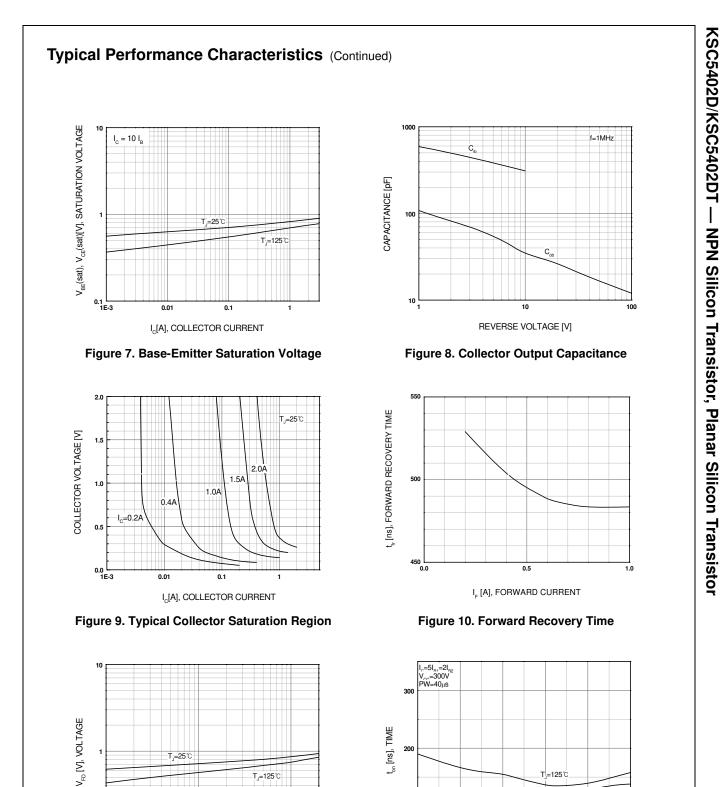
© 2009 Fairchild Semiconductor Corporation KSC5402D/KSC5402DT Rev. C0

Symbol	Parameter	Test Condit	ion	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =1mA, I _E =0		1000	1090		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0		450	525		V
BV_{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0		12	14		V
I _{CES}	Collector Cut-off Current	V _{CES} =1000V, I _{EB} =0	T _A =25°C		0.03	100	μA
			T _A =125°C		1.2	500	μA
I _{CEO}	Collector Cut-off Current	V _{CE} =450V, V _B =0	T _A =25°C		0.3	100	μA
			T _A =125°C		15	500	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} =10V, I _C =0			0.01	100	μA
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =0.4A	T _A =25°C	14	29		
			T _A =125°C	8	17		
		V _{CE} =1V, I _C =1A	T _A =25°C	6	9		
			T _A =125°C	4	6		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =0.4, I _B =0.04A	T _A =25°C		0.25	0.6	V
			T _A =125°C		0.4	1.0	V
		I _C =1A, I _B =0.2A	T _A =25°C		0.3	0.75	V
			T _A =125°C		0.65	1.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =0.4A, I _B =0.04A	T _A =25°C		0.78	1.0	V
			T _A =125°C		0.65	0.9	V
		I _C =1A, I _B =0.2A	T _A =25°C		0.85	1.1	V
			T _A =125°C		0.75	1.0	V
C _{ib}	Input Capacitance	V _{EB} =8V, I _C =0, f=1MH;	Z		330	500	pF
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MH	Ηz		35	100	pF
f _T	Current Gain Bandwidth Product	I _C =0.5A, V _{CE} =10V			11		MHz
V _F	Diode Forward Voltage	I _F =1A	T _A =25°C		0.86	1.5	V
		I _F =0.2A	T _A =25°C		0.75	1.2	V
			T _A =125°C		0.6		V
		I _F =0.4A	T _A =25°C		0.8	1.3	V
			T _A =125°C		0.65		V

Symbol	Parameter	Test Condit	ion	Min.	Тур.	Max.	Units
t _{fr}	Diode Froward Recvery Time (di/dt=10A/µs)	I _F =0.2A I _F =0.4A I _F =1A			540 520 480		ns ns ns
V _{CE} (DSAT)	Dynamic Saturation Voltage	I _C =0.4A, I _{B1} =40mA V _{CC} =300V	@ 1µs		7.5		V
			@ 3µs		2.5		V
		I _C =1A, I _{B1} =200mA V _{CC} =300	@ 1µs		11.5		V
			@ 3µs		1.5		V
RESISTIVE	LOAD SWITCHING (D.C \leq 10%,	Pulse Width=20µs)					
t _{ON}	Turn On Time	I _C =1A,	T _A =25°C		110	150	ns
		I _{B1} =200mA,	T _A =125°C		135		ns
t _{OFF}	Turn Off Time	– I _{B2} =150mA, V _{CC} =300V,	T _A =25°C	0.95		1.25	μS
		$R_L = 300\Omega$	T _A =125°C		1.4		μS
INDUCTIVE	LOAD SWITCHING (V _{CC} =15V)						1
t _{STG}	Storage Time	I _{B1} =40mA, I _{B2} =200mA, Vz=300V, L _C =200H	T _A =25°C		0.56	0.65	μS
			T _A =125°C		0.7		μS
t _F	Fall Time		T _A =25°C		60	175	ns
			T _A =125°C		75		ns
t _C	Cross-over Time		T _A =25°C		90	175	ns
			T _A =125°C		90		ns
t _{STG}	I _{B1} =160mA, T _{A=}	T _A =25°C			2.75	μS	
			T _A =125°C		3		μS
t _F	t _F Fall Time	$L_{C}=200H$ $T_{A}=125$	T _A =25°C		110	175	ns
			T _A =125°C		180		ns
t _C	Cross-over Time		T _A =25°C		125	350	ns
			T _A =125°C		185		ns
t _{STG}	Storage Time	I _C =1A,	T _A =25°C		1.1	1.2	μs
		I _{B1} =200mA,	T _A =125°C		1.35		μs
t _F	Fall Time	I _{B2} =500mA, V ₇ =300V,	T _A =25°C		105	150	ns
		L _C =200μH	T _A =125°C		75		ns
t _C	Cross-over Time		T _A =25°C		125	150	ns
5			T _A =125°C		100		ns



© 2009 Fairchild Semiconductor Corporation KSC5402D/KSC5402DT Rev. C0



© 2009 Fairchild Semiconductor Corporation KSC5402D/KSC5402DT Rev. C0

0.1 └─ 0.01

0.1

I_{FD} [A], CURRENT

Figure 11. Diode Forward Voltage

1.4

100

0.4

r,=25℃

0.8

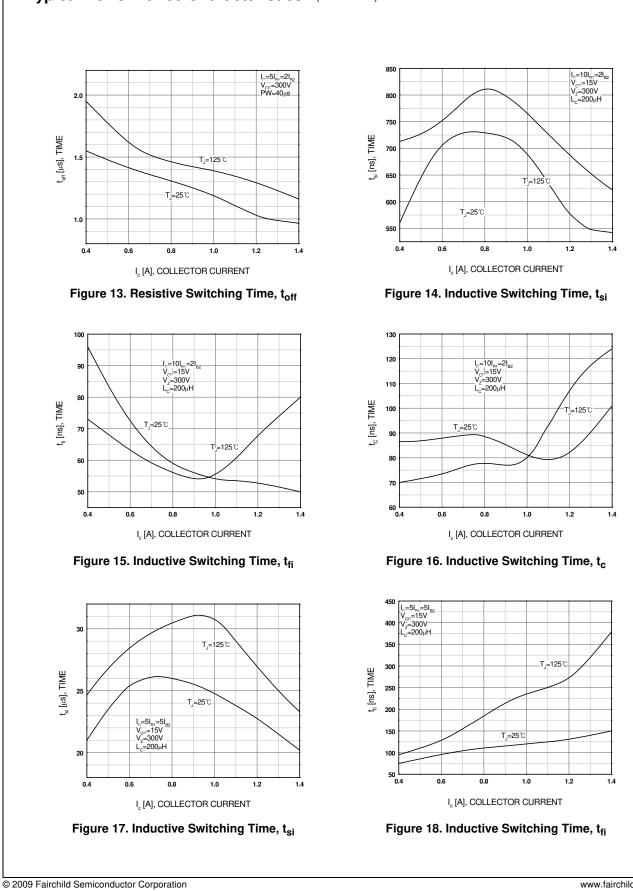
I_c [A], COLLECTOR CURRENT

Figure 12. Resistive Switching Time, ton

1.0

1.2

0.6

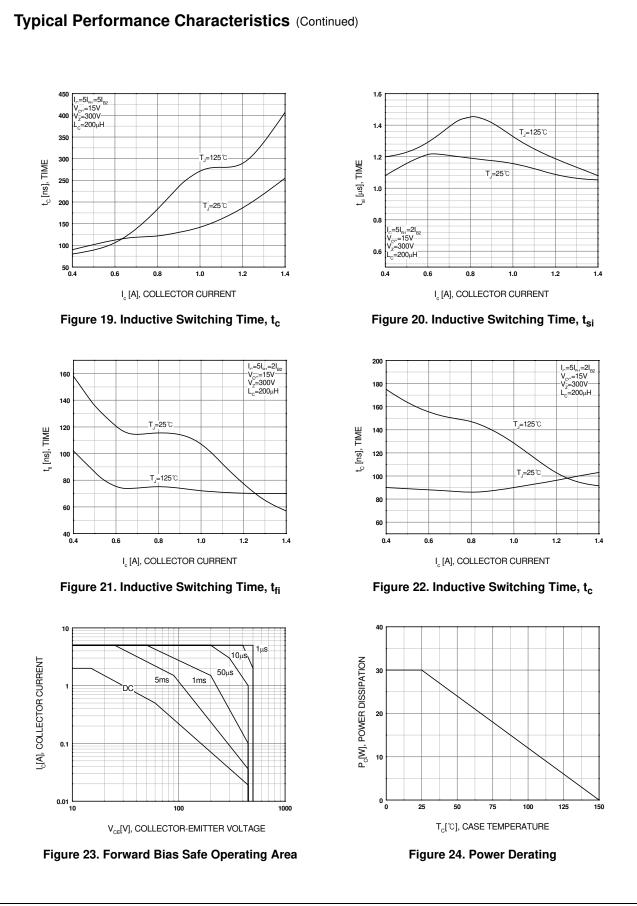


Typical Performance Characteristics (Continued)

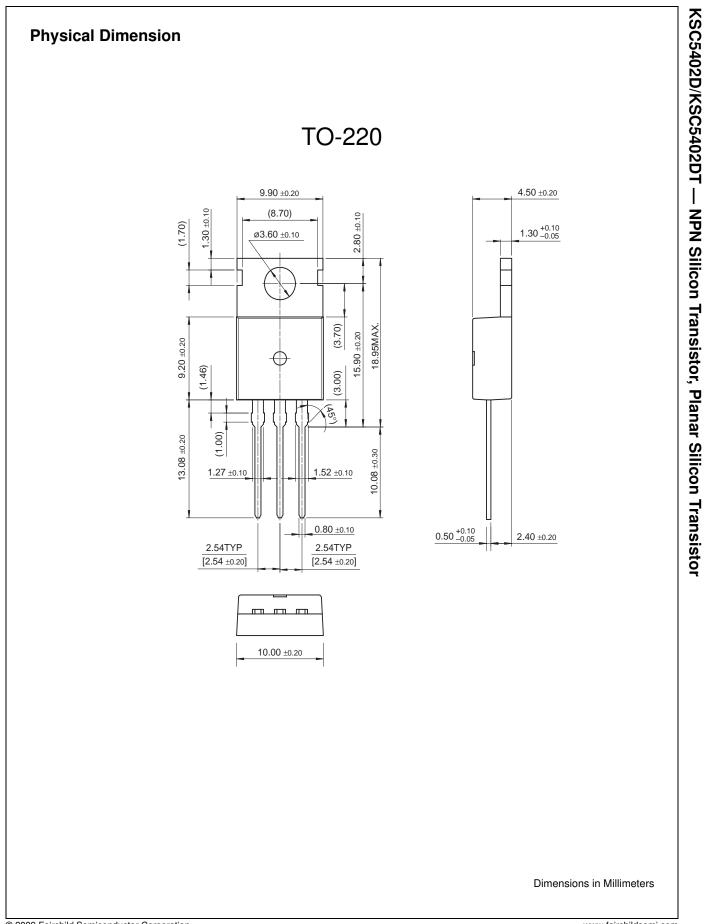
KSC5402D/KSC5402DT Rev. C0

KSC5402D/KSC5402DT — NPN Silicon Transistor, Planar Silicon Transistor

6

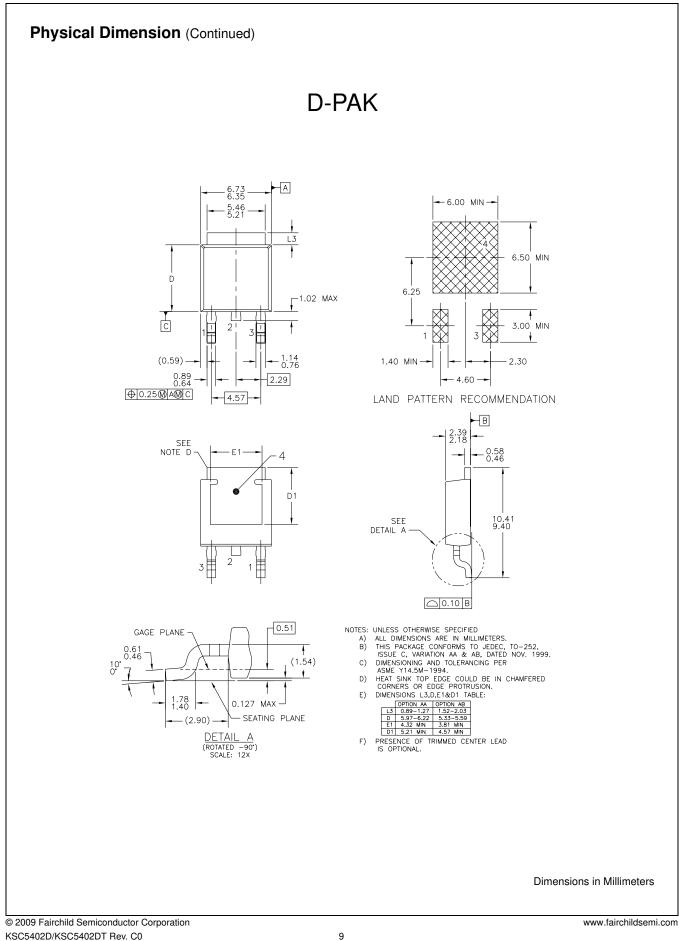


© 2009 Fairchild Semiconductor Corporation KSC5402D/KSC5402DT Rev. C0



8

© 2009 Fairchild Semiconductor Corporation KSC5402D/KSC5402DT Rev. C0





SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

PowerTrench[®]

AccuPower™	FPS™
Auto-SPM™	F-PFS™
Build it Now™	FRFET [®]
CorePLUS™	Global Power Resource
CorePOWER™	Green FPS™
CROSSVOLT™	Green FPS™ e-Series™
CTL™	G <i>max</i> ™
Current Transfer Logic™	GTO™
EcoSPARK [®]	IntelliMAX™
EfficentMax™	ISOPLANAR™
EZSWITCH™*	MegaBuck™
	MICROCOUPLER™
	MicroFET™
F [®]	MicroPak™
T	MillerDrive™
Fairchild®	MotionMax™
Fairchild Semiconductor®	Motion-SPM [™]
FACT Quiet Series™	OPTOLOGIC®
FACT®	OPTOPLANAR®
FAST®	®
FastvCore™	
FETBench™	PDP SPM™
FlashWriter ^{®*}	Power-SPM [™]

PowerXS[™] Programmable Active Droop™ QFĔT⁰ QS™ Quiet Series™ RapidConfigure™ TN Saving our world, 1mW/W/kW at a time™ SmartMax™ SMART START™ SPM® STEALTH™ SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™ SyncFET™ Sync-Lock™ SYSTEM ® GENERAL

puwer TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™* μSerDes™

The Power Franchise[®]



LIHC Ultra FRFET™ UniFFT™ VCX™ VisualMax™ XSTM

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.

1. Life support devices or systems are devices or systems which, (a) are 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Datasheet Identification Product Status		Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC